Electronics & RF hands-on training

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Introduction

Microwave RF radiation



Introduction cont'd



Oscilloscope

NRNO



RF Generator

Soldering iron





VNA

Diaphragms







Resistors, capacitor and transistor ³

Aims

- Explore the application of fundamental radioelectronic components, ability to interpret electronic circuits, and grasp the fundamental principles behind electronic devices
- Provide an overview of the key elements of RF technology and demonstrating how waves behave under different conditions.
 - scenarios without any obstacles as well as situations involving various heterogeneity



Objectives

- Basics of Rf technology
- Determining the wavelength in the waveguide
- Matching quality coefficients (SWR, TWR and $\rho_{\rm h}$)
- Determining total resistance of different irregularities theoretically and

practically



Objectives

- Utilize the reactive dowel for narrow band matching
- Develop skills in calculating the cavity quality factor
- Soldering basic skills
- Evaluating the properties of semiconductors
- Calculation of stage transistor amplifiers



Experiment Procedure: RF Technology





Results and discussion: Determining wavelength

RF Power transmission	Wavelength (cm)		(cu 18) 12		
Coaxial line (λ_w)	10.50	10.00	0 Avelen		
Planar line (λ _w)	10.50	10.86	0 Coaxial line (λw) Planar line (λw) Waveguide (λw) Transmission line		
Waveguide (λ_w)	15.34	15.30	Theoretical Practical		

ONAI

 $\lambda_{\rm w} = \frac{\lambda_{\rm o}}{\sqrt{\varepsilon}}$

$$\lambda_{\rm w} = \frac{\lambda_{\rm o}}{\sqrt{1 - \frac{\lambda_{\rm o}^2}{\lambda_{\rm cr}^2 \varepsilon \mu} \sqrt{\varepsilon \mu}}}$$

Results and discussion: Matching quality coefficients

Setup	Z min (cm)	Z max (cm)	U min (mV)	U max (mV)	SWR ($\frac{U_{max}}{U_{min}}$)
ML	12,9	13.3	173	175	1,01
OW	8.00	11.4	100	200	2.00
ID	4.00	8.40	10.0	32.0	3,20
CD	4.00	6.00	4.00	15.0	3,75
Cal	35.0	10.3	0.00	350	∞



Results and discussion: Total resistance (Theoretically)



$$Y = \frac{1}{Z}$$



$$Z_L^* = \frac{2SWR - j(1 - SWR^2)\sin\varphi}{(SWR^2 + 1) - (SWR^2 - 1)\cos\varphi} \qquad \varphi = \frac{4\pi\Delta z}{\lambda_W}$$

Results and discussion: Total resistance (Smith Chart)





Results and discussion: Total resistance





Results and discussion: total resistance

Setup	Angle (φ)	SWR	Z (theoretical)	Z (VNA)
ML	1.35	1.01	1.00 + j0.01	0.92 + j1.25
OW	5.37	2.00	1.26 + j0.75	0.62 + j0.50
	8 64	3 20	0.36 - i0.37	0.36 - i0.42
	0.04	2.75		
	8.04	3.75	0.31 + J0.38	0.31 + J0.42
S	16.8	×	-	-



Results and discussion: Reactive dowel

Height (mm)	φ	SWR	Z	Y (theoretical)	Y (practical)
0	6.5	1.86	1.75 + j6.5	0.00	-0.14
2	6.3	1.97	1.79 + j4.2	-0.51	-0.20
4	5.8	1.81	1.29 + j2.1	-0.29	-0.35
6	6.1	1.91	1.50 + j3.0	-0.13	-0.27
8	6.0	1.76	1.48 + j2.6	-0.13	-0.29
10	5.9	1.79	1.38 + j2.4	-0.00008	-0.32



Results and discussion: cavity resonator





Voltage divider and RC circuit



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Reverse and forward diode connection







Characteristic V(A) of the diode





Diode application









1uF

Diode application cont'd

3.3uF



47uF



Voltage amplifier





Results cont'd: Amplifier





Conclusions

- Waveguide has a higher wavelength as compared to coaxial and planar lines
- Matched loaded has an ideal SWR value approximately equal to 1
- The reactive dowel does a narrow band matching
- Diodes can assist channel the voltage direction in a circuit
- Increase in capacitance causes the AC behaviour to lean towards DC
- Transistors amplify the input signal power







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